

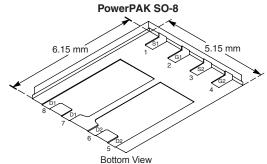
Dual N-Channel 40-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
40	$0.0165 \text{ at V}_{GS} = 10 \text{ V}$	11.3		
	0.020 at V _{GS} = 4.5 V	10.3		

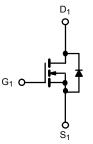
FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFET
- New Low Thermal Resistance PowerPAK® Package
- · Dual MOSFET for Space Savings

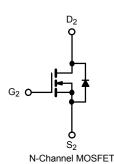




Ordering Information: Si7958DP-T1-E3 (Lead (Pb)-free) Si7958DP-T1-GE3 (Lead (Pb)-free and Halogen-free)







ABSOLUTE MAXIMUM RATINGS	$T_A = 25 ^{\circ}C$, unles	ss otherwise n	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V_{DS}	40		V
Gate-Source Voltage		V_{GS}	± 20		V
Continuous Drain Current /T 150 °C\a	T _A = 25 °C	- I _D	11.3	7.2	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		9.0	5.8	
Pulsed Drain Current		I _{DM}	40		Α
Continuous Source Current (Diode Conduction) ^a		I _S	2.9	1.2	
Single Avalanche Current	L = 0.1 mH	I _{AS}	35		
Single Avalanche Energy	•		61		mJ
Mandana Barra Birahadi ad	T _A = 25 °C	- P _D	3.5	1.4	W
Maximum Power Dissipation ^a	T _A = 70 °C		2.2	0.9	VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150 260		°C
Soldering Recommendations (Peak Temperature) ^{b, c}		-			

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	t ≤ 10 s	R _{thJA}	26	35	°C/W
Maximum Junction-to-Ambient	Steady State		60	85	
Maximum Junction-to-Case (Drain)	Steady State	R_{thJC}	2.2	2.7	

Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

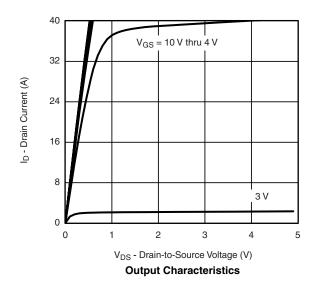
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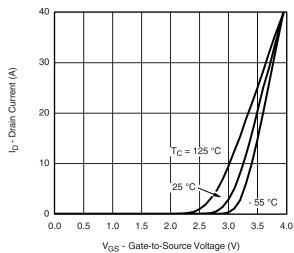


Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static	<u> </u>		1	<u> </u>	l l	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1		3	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 40 V, V _{GS} = 0 V			1	
		$V_{DS} = 40 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5	μΑ
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α
Drain-Source On-State Resistance ^a	D	V _{GS} = 10 V, I _D = 11.3 A		0.013	0.0165	
	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 10.3 \text{ A}$		0.016	0.020	Ω
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 11.3 A		30		S
Diode Forward Voltage ^a	V_{SD}	$I_S = 2.9 \text{ A}, V_{GS} = 0 \text{ V}$		0.8	1.2	V
Dynamic ^b			•			
Total Gate Charge	Q_g			50	75	nC
Gate-Source Charge	Q_{gs}	$V_{DS} = 20 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 11.3 \text{ A}$		8.8		
Gate-Drain Charge	Q _{gd}			10.4		
Gate Resistance	R_{g}	f = 1 MHz		1.9		Ω
Turn-On Delay Time	t _{d(on)}			17	30	
Rise Time	t _r	V_{DD} = 20 V, R_L = 20 Ω		17	30	ns
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		66	100	
Fall Time	t _f			17	30	
Source-Drain Reverse Recovery Time	t _{rr}	$I_{\rm F} = 2.9 \text{A}, \text{dI/dt} = 100 \text{A/}\mu\text{s}$		31	60	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



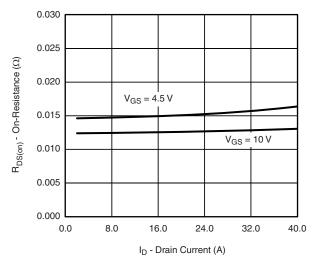


Transfer Characteristics

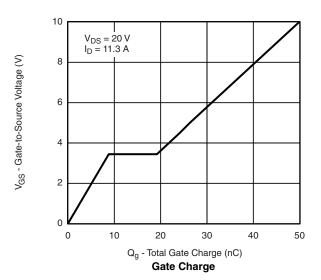
Notes: a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

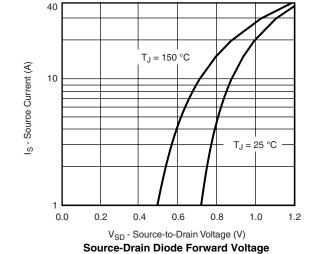


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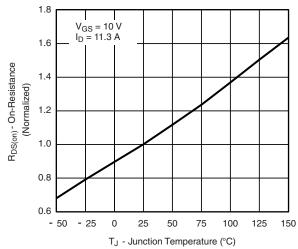
On-Resistance vs. Drain Current



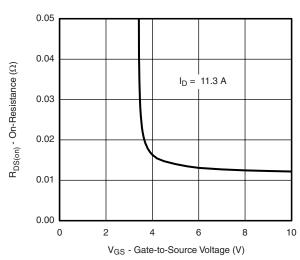


4000 3500 3000 $\mathsf{C}_{\mathsf{iss}}$ C - Capacitance (pF) 2500 2000 1500 1000 Coss C_{rss} 500 0 0 8 16 24 32 40

V_{DS} - Drain-to-Source Voltage (V) **Capacitance**



On-Resistance vs. Junction Temperature

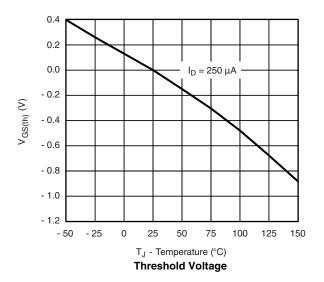


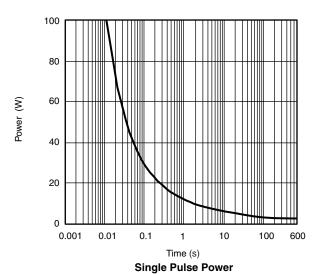
On-Resistance vs. Gate-to-Source Voltage

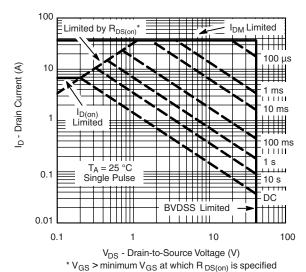
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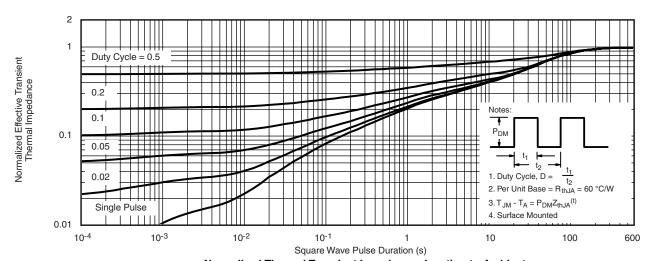
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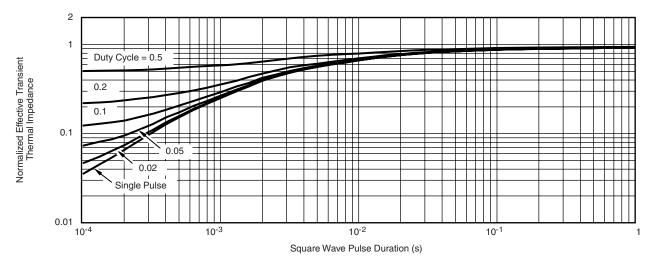
Safe Operating Area, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72661.

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